

# **AFRL-RZ-WP-TP-2012-0098**

# GROWTH OPTIMIZATION OF YBa<sub>2</sub>NbO<sub>6</sub> BUFFER LAYERS (POSTPRINT)

N.A. Yust, T.J. Haugan, J.C. Tolliver, and P.N. Barnes

**Mechanical Energy Conversion Branch Energy/Power/Thermal Division** 

S. Sathiraju

**NRC** 

R.N. Nekkanti

UES, Inc.

I. Maartense

**Materials and Manufacturing Directorate** 

**FEBRUARY 2012** 

Approved for public release; distribution unlimited.

See additional restrictions described on inside pages

# STINFO COPY

© 2004 Materials Research Society

AIR FORCE RESEARCH LABORATORY
PROPULSION DIRECTORATE
WRIGHT-PATTERSON AIR FORCE BASE, OH 45433-7251
AIR FORCE MATERIEL COMMAND
UNITED STATES AIR FORCE

# REPORT DOCUMENTATION PAGE

Form Approved OMB No. 0704-0188

2 DATEC COVEDED /From

The public reporting burden for this collection of information is estimated to average 1 hour per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Department of Defense, Washington Headquarters Services, Directorate for Information Operations and Reports (0704-0188), 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302. Respondents should be aware that notwithstanding any other provision of law, no person shall be subject to any penalty for failing to comply with a collection of information if it does not display a currently valid OMB control number. PLEASE DO NOT RETURN YOUR FORM TO THE ABOVE ADDRESS.

I. REPORT DATE (DD-IVIIVI-TT)	Z. KEPUKI	ITPE	3. DATES CO	VERED (From - 10)
February 2012	Con	ference Paper Postprint	01 Janua	ary 2002 – 01 January 2004
4. TITLE AND SUBTITLE				5a. CONTRACT NUMBER
GROWTH OPTIMIZATION OF YI	Ba <sub>2</sub> NbO <sub>6</sub> B	UFFER LAYERS (POSTPR	INT)	In-house
				5b. GRANT NUMBER
				5c. PROGRAM ELEMENT NUMBER 62203F
6. AUTHOR(S)				5d. PROJECT NUMBER
N.A. Yust, T.J. Haugan, J.C. Tollive	r, and P.N	. Barnes (AFRL/RZPG)		3145
S. Sathiraju (NRC)				5e. TASK NUMBER
R.N. Nekkanti (UES, Inc.)				32
Iman Maartense (AFRL/RX)				5f. WORK UNIT NUMBER
				314532Z9
7. PERFORMING ORGANIZATION NAME(S) AN	D ADDRESS	(ES)		8. PERFORMING ORGANIZATION
Mechanical Energy Conversion Branch (AFI	UES, Inc.		REPORT NUMBER	
Energy/Power/Thermal Division Air Force Research Laboratory, Propulsion Directorate Wright-Patterson Air Force Base, OH 45433-7251 Air Force Materiel Command, United States Air Force		Air Force Research Laboratory Materials and Manufacturing Directorate (AFRL/RX) Wright-Patterson AFB, OH 45433-7750		AFRL-RZ-WP-TP-2012-0098
NRC		Air Force Materiel Command United States Air Force		
9. SPONSORING/MONITORING AGENCY NAM Air Force Research Laboratory Propulsion Directorate	E(S) AND AC	DDRESS(ES)		10. SPONSORING/MONITORING AGENCY ACRONYM(S) AFRL/RZPG
Wright-Patterson Air Force Base, OH 45433-7251 Air Force Materiel Command United States Air Force				11. SPONSORING/MONITORING AGENCY REPORT NUMBER(S) AFRL-RZ-WP-TP-2012-0098
12. DISTRIBUTION/AVAILABILITY STATEMENT Approved for public release; distribu		iited.		

#### 13. SUPPLEMENTARY NOTES

Conference paper published in the proceedings of the *Materials Research Society Symposium*, Vol. EXS-3, 2004. © 2004 Materials Research Society. The U.S. Government is joint author of the work and has the right to use, modify, reproduce, release, perform, display, or disclose the work. Work on this effort was completed in 2004. "Vj ku"r cr gt "j cu"eqmqt "eqpvgpv0"

PA Case Number: ASC-03-3094; Clearance Date: 06 Dec 2004.

# 14. ABSTRACT

The growth optimization of  $YBa_2NbO_6$  (YBNO) buffer layers on LaAlO3 (100), MgO (100) single crystals, and IBAD MgO buffered Inconel substrates has been investigated. X-ray diffraction confirms the epitaxial growth of highly h00 oriented YBNO thin films on single crystal substrates and IBAD MgO buffered Inconel substrates. The best average surface roughness of the YBNO films deposited on buffered substrates is 2 nm. The critical temperature ( $T_c$ ) of  $YBa_2Cu_3O_{7-x}$  (Y-123) thin films deposited on these YBNO buffer layers ranges from 80 to 87 K. The deposition of YBNO may be further optimized and the IBAD MgO layers were only of sufficient quality to test for compatibility and epitaxial growth of the new buffer. Hence, the results presented here are preliminary in nature and can be improved upon.

#### 15 SUBJECT TEDMS

diffraction, crystal, buffered, inconel, epitaxial, films, substrates, layers, growth, investigated, sufficient, preliminary, critical

16. SECURITY	CLASSIFICATIO	N OF:	17. LIMITATION	18. NUMBER	19a. NAME OF RESPONSIBLE PERSON (Monitor)	
u o	<b>b. ABSTRACT</b> Unclassified	c. THIS PAGE Unclassified	OF ABSTRACT: SAR	10	Timothy J. Haugan  19b. TELEPHONE NUMBER (Include Area Code) N/A	

# Growth Optimization of YBa2NbO6 Buffer Layers

S. Sathiraju<sup>1</sup>, N.A. Yust, R.N. Nekkanti<sup>2</sup>, I. Maartense<sup>3</sup>, A.L. Campbell<sup>3</sup>, T.L. Peterson<sup>3</sup>, T.J. Haugan, J.C. Tolliver, P.N. Barnes

<sup>1</sup>NRC, <sup>2</sup>UES Inc., <sup>3</sup>AFRL/MLP Air Force Research Laboratory, PRPG, 2645 Fifth St., Bldg. 450, Wright-Patterson AFB, OH 45433

Q.X. Jia, P.N. Arendt Superconductor Technology Center, Los Alamos National Laboratory, NM 87545

#### **ABSTRACT**

The growth optimization of YBa<sub>2</sub>NbO<sub>6</sub> (YBNO) buffer layers on LaAlO<sub>3</sub> (100), MgO (100) single crystals, and IBAD MgO buffered Inconel substrates has been investigated. X-ray diffraction confirms the epitaxial growth of highly *h00* oriented YBNO thin films on single crystal substrates and IBAD MgO buffered Inconel substrates. The best average surface roughness of the YBNO films deposited on buffered substrates is 2 nm. The critical temperature (T<sub>c</sub>) of YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub> (Y-123) thin films deposited on these YBNO buffer layers ranges from 80 to 87 K. The deposition of YBNO may be further optimized and the IBAD MgO layers were only of sufficient quality to test for compatibility and epitaxial growth of the new buffer. Hence, the results presented here are preliminary in nature and can be improved upon.

# **INTRODUCTION**

The quality of superconducting films epitaxially grown highly depends on the substrate choice. It is well known that  $SrTiO_3(100)$ ,  $LaAlO_3(100)$ , YSZ(100) and MgO(100) are suitable single crystal substrates for producing high quality superconducting thin films, especially  $YBa_2Cu_3O_{7-x}$  (Y123). However, it has been reported that for 123 films deposited on MgO single crystal, an interlayer of barium salt is formed at the interface if the processing temperature is above 700 °C [1]. Also, another problem reported with the films grown on MgO is the presence of  $45^{\circ}$  in-plane rotated grains which degrades the crystalline quality of the deposited  $RBa_2Cu_3O_x$  (where R = Y, rare earths) [2,3]. A possible solution is to use a suitable buffer layer on the MgO substrate for the growth of the subsequent Y123 film. The same concept can be extended to coated conductor applications.  $YBa_2NbO_6$  (YBNO) has a cubic perovskite structure (a ~ 8.4 Å) and has moderate dielectric properties [4]. In this paper we report the growth of  $YBa_2NbO_6$  compound as a new dielectric buffer layer on MgO(100) and  $LaAlO_3(100)$  single crystal, and  $IBAD\ MgO$  buffered Inconel substrates for the subsequent deposition of Y123 thin films.

## **EXPERIMENTAL**

YBa<sub>2</sub>NbO<sub>6</sub> target has been prepared with 4N purity Y<sub>2</sub>O<sub>3</sub>, BaCO<sub>3</sub> and Nb<sub>2</sub>O<sub>5</sub> powders by the standard solid-state synthesis method. LPX 304i Kr F excimer Laser with 248nm wavelength

was used to deposit YBNO films and subsequent Y-123 thin film deposition on various substrates. Substrate block temperatures are varied between room temperature to 850 °C. Other parameters such as O<sub>2</sub> (250 mTorr) pressure, Substrate Target distance (7cm), laser pulse energy 3J/cm<sup>2</sup> and pulse frequency (6Hz) are kept constant during the YBNO deposition. The texture of IBAD MgO buffered Inconel substrates obtained from LANL is 4-6°. Films were characterized by x-ray diffraction (XRD), atomic force microscopy (AFM), and ac susceptibility measurements.

# **RESULTS AND DISCUSSION**

XRD results confirm that YBNO films deposited on single crystal substrartes are epitaxial and transparent (Figure 1). YBNO films deposited on IBAD MgO buffered Inconel are highly h00 oriented. Epitaxial YBNO films were grown between  $800-850^{\circ}$  C on single crystal substrates and IBAD MgO buffered Inconel metal substrates. Films deposited at room temperature are amorphous. The surface morphology of the YBNO films reveals out growths even though the average surface roughness is only 2-4 nm (Figure 2). The average surface roughness Ra of YBNO films determined from AFM studies is listed in Table 1. Highly c-axis oriented Y-123 film was deposited on CeO<sub>2</sub>/YBNO/IBADMgO/Inconel. Critical temperatures ( $T_c$ ) determined from AC susceptibility measurements vary about 80-89 K on different substrates (Table 2). The broadening of the  $\chi$  or  $\chi$  curves suggest that there is a weakly coupled grain structure (Figure 3). The deposition of YBNO may be further optimized as the IBAD MgO samples were only of sufficient quality to test for compatibility and epitaxial growth of the new buffer. Hence, the results presented here are preliminary in nature and can be improved upon in future work.

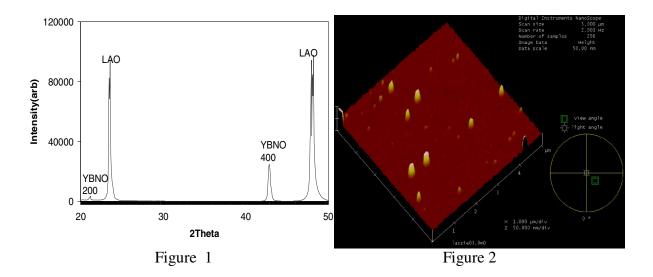


Figure 1. XRD pattern of *epitaxial* YBNO film on LaAlO<sub>3</sub> (LAO)

Figure 2. AFM micrograph of YBNO film deposited on IBAD MgO substrate

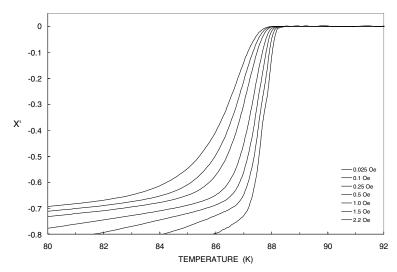


Figure 3. AC susceptibility data of Y-123 film deposited on CeO<sub>2</sub>/YBNO/IBAD MgO/Inconel

Table 2. YBNO Surface roughness data from AFM analysis

Substrate	YBNO RMS roughness (nm)	T <sub>c</sub> of Y123 film (from ac susceptibility)
LaAlO <sub>3</sub> (100)	3-7	82
MgO (100)	2-6	84
IBAD MgO	2-4	86
Inconel	5-40	80

## **CONCLUSIONS**

Epitaxial YBNO films were grown on single crystal as well as IBAD MgO buffered metal substrates. Initial results of Y123 thin films deposited on these buffer layers are promising for coated conductor applications. Further optimization of the buffer layer is in progress.

# **ACKNOWLEDGEMENTS**

Sathiraju acknowledges National Research Council, National Academy of Sciences, Air Force Office of Scientific Research, and the Propulsion Directorate of Air Force Research Laboratory for SRA fellowship and research support.

# **REFERENCES**

- 1. Koinuma et al., *Jpn. J. Appl. Phys.* **27,** L1216 (1988)
- 2. Mukadia M et al *Supercond. Sci. Tech.* **12**, 890 (1999)
- 3. Yoshitake T et al IEEE Trans Appl. Supercon. 9, 3058 (1999)
- 4. Babu T.G. N and Koshy J. Solid state Chem. **126**, 202 (1996)